

Heat Affected Zone in the Wire Electrode During Electronic Flame Off in Bonding

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Abstract

In the wirebonding process process of microelectronic packaging, electric discharge heating is the first step. Typically, the discharge occurs between two electrodes, one element is a wire cylinder (anode) and the other element is a flat plate (cathode). The heat of the discharge causes the wire electrode tip to melt. Surface tension causes the molten metal to roll up into a ball. When a sufficient amount has melted, the discharge is terminated and the molten ball is allowed to solidify. Subsequently, the tip material is bonded to the chip bond pad. The wire spooled out through a capillary is looped over to form a second bond to the lead frame. Subsequently, the wire is torn off and, typically, the wire electrode is left with a bent tip, and the electronic flame off (EFO) process is repeated for the next pair of bonds. In this paper, the ball formation process is experimentally simulated using an up-scaled (60 x) model with a copper wire (1.55 mm diameter) having a bent tip. The discharge occurs in a 90 OCV arc chamber operating at a vacuum of 10-15 mm Hg with air as cover gas. The control variables are current, voltage, arc duration, arc gap, and chamber pressure. Thermocouples embedded in the wire are used to obtain the transient temperature variation. This temperature history is then used to deduce the heat transfer from the arc to the wire by solving the unsteady energy equation subject to appropriate boundary conditions. The Laplace transform technique is used for this purpose. Microscopic grain boundary studies of the solidified tips are carried out to ascertain the nature of solidification, the extent of porosity, and the heat affected zone (HAZ) in the wire electrode. Results for the transient current-power characteristics and the heat transfer are presented along with those for the metallographic studies. Based on such studies, optimal characteristics of initial tip shapes may be developed which influence the design of the capillary and the reliability of the joint. In fine pitched packaging, low loops of the wire interconnect are essential. The shape and the height of the loop is determined by the HAZ and this has motivated the current study. The formation of balls with minimum departure from sphericity, low porosity, along with a small HAZ is a challenge still faced in the industry.

Key words:

Fine pitch ball-bonding, Electronic Flame Off (EFO), Heat affected zone, Experimental scale up, and Heat transfer.

1. Introduction

The wirebonding packaging process uses an EFO discharge between two electrodes causing a portion of one of them (the cylindrical wire anode) to melt, roll up into a ball, and later solidify. Specifically, an important part of Very Large Scale Integrated (VLSI) circuit chip assembly and packaging is the process of making electrical interconnections between the chip and a lead frame, which is ultimately connected to the other external electrical components. The most effective method of achieving this interconnection is the ball-wedge bonding process¹ which consists of the ball bonding step at one end of the interconnec-

tion and the wedge bonding step at the other end. The interconnection is made using a very fine metal wire (~25µm in diameter). The process involves melting the tip of the wire with an electrical discharge that is struck between the wire (anode) and a flat plate (cathode). The discharge process is commonly known in the industry as Electronic Flame Off (EFO). As the melting progresses, the molten wire rolls up by surface tension and forms a liquid sphere which grows in size until the discharge is terminated. This is followed by solidification of the spherical melt due to heat loss by conduction up the wire and to the surroundings. The resulting spherical tip is then ultrasonically (or thermosonically) bonded to the chip. The entire process has a duration of a few milliseconds. Then, the wire is wedge bonded to the chip's lead frame at a prescribed length from the ball. The length of wire between the two bonds is kept at a minimum so as to have the smallest possible chip profile as this length forms a loop from the bond pad on the chip to the lead frame. The height of this loop is affected by the length of the Heat Affected Zone (HAZ) along the wire axis from the ball. The length of the heat affected zone (HAZ) in the wire anode depends on the magnitude of the conductive heat flux along the axis of the wire during the EFO discharge process. The HAZ tends to be more brittle than the unaffected zone. The wire is looped (beyond the HAZ) and a second bond is made on the mounting lead frame, ultrasonically (without melting). Subsequently, the wire is torn off and the end is hooked from the deformation caused during the second bond. The EFO process is then repeated, starting from this hooked end.

Good balls are characterized by minimum departure from sphericity and low porosity that ensure good bond quality and therefore a secure interconnection. Much work has been done on wirebonding with nonprecious metals²⁻¹³. These studies have all been on the real (25 µm) scale. Harman¹⁴ has provided an excellent compendium of factors affecting the strength and durability of wirebonds. The experimental and theoretical studies of the authors on ball formation¹⁵⁻²⁶ have helped make significant advances in modeling the discharge and subsequent ball formation process.

In this study, the researchers report discharge current and power characteristics, temperature transients, heat transfer calculations, and metallographic studies using a copper wire anode in a large scale model to assess the heat affected zone (HAZ).

2. Theory

The most important parameters governing the melting and resolidification of the anode tip are the wire diameter (d), the discharge current (I), the voltage drop (ΔV), the gap (G) between the electrodes, the cover gas pressure (p), and the duration of discharge (t). In wirebonding, these processes typically occur over very short time scales (~1 millisecond) and small length scales (~25 µm). Direct experimental observations of the process be-

come very difficult. Cohen & Ayyaswamy²⁷ have performed a dimensional analysis to identify the principal dimensionless parameters governing such processes. These parameters are identified as wire diameter (d) to gap length ratio, $\frac{d}{G}$, Surface tension force to weight ratio, $\frac{3\sigma}{2\rho R^2 g}$, the discharge parameter, $\frac{I\Delta V t}{pG^3}$, the pressure parameter, $\frac{p}{\rho g d}$, and the ratio of surface tension to electromagnetic body forces, $\frac{2\pi d\sigma}{JBv}$. In this case, $J = 4I/\pi d^2$ is the current density, B is the magnetic induction, estimated to be at most $\mu I/\pi d$, where, μ is the magnetic permeability, and v is the volume of the ball.

The researchers calculated these parameters for the real scale and for the laboratory (enlarged) scale. They found that the dimensionless parameters are of extreme size and they argue that the physical problem has already achieved its limiting form, insensitive to further variation in these parameters. Thus, precise correspondence on the two scales would be unnecessary.

Scaling gold up 60 x, which would be (barely) parametrically permitted, is prohibitively costly. For large length scale ball formation, copper was used. The researchers regarded all the dimensionless similarity parameters as having achieved their limiting solution state by virtue of their extreme size. The fineness parameter is weakly small (on the large scale) but the discharge is still between a wire and a plane. For larger balls of heavier metals, the surface tension parameter is only weakly large so that the ball is shaped like a pendent drop rather than a near perfect sphere. This is easily accounted for as a perturbation in the numerical solutions. With this minor exception, the researchers argue that their upscaled experimental realization of ball formation by electric discharge heating of the end of a wire closely corresponds to the real scale process. Clearly, fine details of the process are scale dependent. In performing a computational simulation, the authors found that the (boundary) condition on heat flux at the plasma-wire tip boundary is not known due to the empiricism in the energy "accommodation coefficient." In the large scale experiments, the authors implanted fine wire thermocouples in the wire samples at two locations above where the ball is formed. Recording the transient temperature response during the discharge, the heat flux from the discharge plasma to the wire can be inferred as described in the next section.

3. Calculation of Heat Transfer up the Wire

An important part of this study is the determination of the heat transferred from the arc to the wire. The extent of the Heat Affected Zone (HAZ) is determined by the rate of heat transfer to the wire tip, and the heat flux along the axis of the wire. As described in a later section, thermocouples are used to obtain the transient temperature variation at two axial locations on the wire. The determination of the heat transfer by conduction up the wire, based on these temperature histories, involves the solution of the

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transient heat transfer equation for the wire. The histories are applied as time dependent temperature boundary conditions for the heat transfer problem. The axial (one-dimensional) conduction, storage, and heat loss by convection and radiation from the surface of the wire segment during the discharge, are taken into account by a transient energy balance, of the form,

$$\frac{\partial T}{\partial t} = a \frac{\partial^2 T}{\partial x^2} - \frac{P}{A\rho c_p} [\varepsilon\sigma(T^4 - T_a^4) + h_c(T - T_a)],$$

for all x in $(0,L)$, t in $(0,t_d)$ (1)

where $T(x, t)$ is the temperature at any location x along the axis of the wire at time t . x is measured from the location of the first thermocouple. This location is chosen such that, at the end of the discharge, it is located close to the neck between the ball and straight wire. The authors assume that the wire is slender enough for the radial temperature gradients to be considered negligible, facilitating a one-dimensional treatment. Constant properties are assumed to facilitate analytical solutions. In this case, t_d is the duration of the discharge and L is the length of the wire segment between the two thermocouple locations. T_a is the ambient temperature, and a , c_p and ε are the thermal diffusivity, specific heat, and surface emissivity of the wire material, respectively. P and A are the perimeter and cross-sectional area of the wire. σ is the Stefan-Boltzmann constant and h_c is the convective heat transfer coefficient at the wire surface. To simplify the solution of the transport equation, the authors linearize the radiation term by employing the concept of a radiative heat transfer coefficient defined as follows,

$$h_r = \varepsilon\sigma \frac{T^4 - T_a^4}{T - T_a} = \varepsilon\sigma(T + T_a)(T^2 + T_a^2) \approx \varepsilon\sigma(\hat{T} + T_a)(\hat{T}^2 + T_a^2) \quad (2)$$

where \hat{T} is the average temperature of the wire during the discharge. Combining the convective and radiative heat transfer coefficients, one can write,

$$h = h_c + h_r$$

For the duration of the discharge, the transient temperature variation is sufficiently accurately represented by a linear function of time as indicated by the temperature data obtained during the discharge process. Therefore, the initial condition and the boundary conditions are as necessary,

$$\text{at } t=0 \quad T(x, t) = T_a, \quad \text{for all } x \text{ in } (0,L) \quad (3)$$

$$\text{at } x=0 \quad T(x, t) = (T_{f0} - T_a) \frac{t}{t_d} + T_a, \quad \text{for all } t \text{ in } (0,t_d) \quad (4)$$

$$\text{at } x=L \quad T(x, t) = (T_{fL} - T_a) \frac{t}{t_d} + T_a, \quad \text{for all } t \text{ in } (0,t_d) \quad (5)$$

$$\text{Here, } T_{f0} = T(0, t_d) \text{ and } T_{fL} = T(L, t_d) \quad (6)$$

Next, the authors nondimensionalize the transport equation by defining the following non-dimensional (*) quantities.

$$\theta^* = \frac{T - T_a}{T_{f0} - T_a}, \quad t^* = \frac{t}{t_d}, \quad x^* = \frac{x}{L}, \quad (7)$$

where T_{f0} is the reference temperature. Then, the non-dimensional heat transport equation, and the initial and boundary conditions constitute the following boundary value-initial value problem.

$$\frac{\partial \theta}{\partial t} = Fo \frac{\partial^2 \theta}{\partial x^2} - \left(\frac{4ht_d}{d\rho c_p} \right) \theta, \quad \text{for all } x \text{ in } (0,1), \quad t \text{ in } (0,1) \quad (8)$$

$$\text{at } t=0 \quad \theta(x, t) = 0, \quad \text{for all } x \text{ in } (0,1) \quad (9)$$

$$\text{at } x=0 \quad \theta(x, t) = t, \quad \text{for all } t \text{ in } (0,1) \quad (10)$$

$$\text{at } x=1 \quad \theta(x, t) = \frac{T_{fL} - T_a}{T_{f0} - T_a} t \equiv Kt(\text{say}), \quad \text{for all } t \text{ in } (0,1) \quad (11)$$

In the above, the asterisks for dimensionless quantities have been omitted for convenience. In this case, $Fo = at_d/L^2$ is the Fourier number.

Due to the presence of the time-dependent boundary conditions, the Laplace transform method is employed to solve the above fully transient formulation. For this purpose, the following transformation of the dependent variable θ is used.

$$\theta = \bar{\theta} e^{-Bt} \quad (12)$$

where $B = \frac{4ht_d}{d\rho c_p}$. The transformed problem then becomes,

$$\frac{\partial \bar{\theta}}{\partial t} = Fo \frac{\partial^2 \bar{\theta}}{\partial x^2}, \quad \text{for all } x \text{ in } (0,1), \quad t \text{ in } (0,1) \quad (13)$$

$$\text{at } t=0 \quad \bar{\theta}(x, t) = 0, \quad \text{for all } x \text{ in } (0,1) \quad (14)$$

$$\text{at } x=0 \quad \bar{\theta}(x, t) = t e^{Bt}, \quad \text{for all } t \text{ in } (0,1) \quad (15)$$

$$\text{at } x=1 \quad \bar{\theta}(x, t) = Kt e^{Bt}, \quad \text{for all } t \text{ in } (0,1) \quad (16)$$

Performing a Laplace transformation over the time domain, $[t \rightarrow s]$ such that,

$$L [\bar{\theta}(x, t)] = \bar{\theta}(x, s)$$

The researchers obtained a second order differential equation in x with boundary conditions:

$$\begin{aligned} \frac{\partial^2 \bar{\theta}}{\partial x^2}(x, s) - \frac{s}{Fo} \bar{\theta}(x, s) &= 0, \\ \bar{\theta}(0, s) &= \frac{1}{(s-B)^2}, \\ \bar{\theta}(1, s) &= \frac{K}{(s-B)^2}, \end{aligned}$$

The solution to this equation is of the form,

$$\bar{\theta}(x, s) = \frac{1}{(s-B)^2} \left[K \frac{\sinh qx}{\sinh q} + \frac{\sinh q(1-x)}{\sinh q} \right], \quad (17)$$

where $q = \sqrt{\frac{s}{Fo}}$. The temperature gradient in the transformed domain is written as follows,

$$\frac{\partial \bar{\theta}}{\partial x}(x, s) = \frac{1}{(s-B)^2} \left\{ \frac{Kq \cosh qx}{\sinh q} - q \frac{\cosh q(1-x)}{\sinh q} \right\} \quad (18)$$

The researchers invert the Laplace transform using the Bromwich contour integral formula²⁸. The transform has a second order pole at $s=B$ and simple poles at $q = \sqrt{s/Fo} = in\pi$, where $n = 1, 2, 3, \dots$. Employing Jordan's Lemma and Cauchy's residue theorem, one would obtain the Laplace inverse after some algebra²⁸. Also, inverting the transformation $[\theta \rightarrow \bar{\theta}]$, one can obtain the following,

$$\begin{aligned} \frac{\partial \theta}{\partial x}(x, t) = & (t\hat{q} + \frac{1}{2\hat{q}Fo}) \left[K \frac{\cosh \hat{q}x}{\sinh \hat{q}} - \frac{\cosh \hat{q}(1-x)}{\sinh \hat{q}} \right] \\ & + \frac{1}{2Fo} \left[Kx \frac{\sinh \hat{q}x}{\sinh \hat{q}} - (1-x) \frac{\sinh \hat{q}(1-x)}{\sinh \hat{q}} \right] \\ & - \frac{\coth \hat{q}}{2Fo} \left[K \frac{\cosh \hat{q}x}{\sinh \hat{q}} - \frac{\cosh \hat{q}(1-x)}{\sinh \hat{q}} \right] \\ & + \sum_{n=1}^{\infty} [1 - (-1)^n K \frac{2n^2\pi^2 Fo}{(n^2\pi^2 Fo + B)^2} \cos n\pi x e^{-(n^2\pi^2 Fo + B)t}] \end{aligned} \quad (19)$$

where $\hat{q} = \sqrt{B/Fo}$. The above instantaneous heat flux may be integrated over time at any location x . Thus, the cumulative heat flux up the wire is computed at $x = 0$. This is extrapolated to the wire tip to account for the transient energy storage in the segment that forms the ball. When this is multiplied by the wire cross-sectional area, one can obtain the heat transfer, Q_k , up the wire axis. This value of Q_k is added to the other heat quantities Q_m (heat of melting), and Q_{hr} (heat lost to convection and radiation from the tip) to obtain the total heat transfer, Q_w , to the wire. Next, a brief description of the experimental setup and procedure is provided, followed by results and discussion.

4. Experimental Setup and Procedure

In order to simulate the real scale conditions, a special enlarged (60x) capillary was constructed to deform the tips of the up-scaled wire samples (1.55 mm diameter) in exactly the same way as happens in wirebonding (see Figure 1). The up-scaled arc chamber is constructed of concentric cylinders of stainless steel tubing approximately 0.3 m high. The electrode holders are made up of two threaded hollow copper tubes. The threaded copper tubes are mated with similarly threaded machined copper fittings with receptacles to hold the electrode tips. An aluminum plug with a centered drilled hole to accommodate the 1.55 diameter copper wire is press fitted into the anode receptacle. The

entire anode assembly can be pneumatically actuated. This facilitates arc initiation by electrode contact.

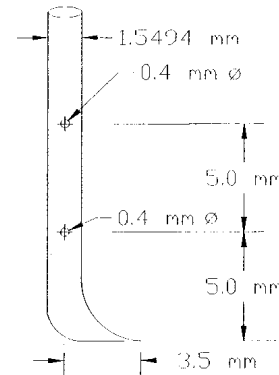


Figure 1. Wire sample drawing.

The cathode cylinder has a flat 1% thoriated tungsten tip. The arc chamber is evacuated to 10-15 mm Hg. The electrical equipment consists of a 40 kW, 90 V DC open circuit voltage power supply that rectifies a 480 V 3-ph ase, 60 Hz AC supply. An LC filter reduces the output ripple to less than 2% with the dominant frequency of 360 Hz. A 0 - 6 ohm variable ballast resistor placed in series with the arc current is used to control and vary the arc current. Data are recorded using a personal computer (PC) with a data acquisition (DAQ) board. This is supported by suitable software for data management, manipulation, and display. A 0.158 Ω resistor is placed in series with the arc current and a 56 k Ω /1.02 M Ω voltage divider is placed in parallel with the arc voltage so that both signals are reduced to a level that can be accepted by the data acquisition board. Fine wire (50.8 μ m) type K (Chromel-Alumel) thermocouples are used to measure the temperatures at two different locations along the length of the wire to obtain the transient thermal characteristics. The thermocouple hot junctions are cemented into 0.4 mm diameter through-holes at distances of 5 mm and 10 mm from the deformed tips of the wire samples. The depth of immersion of the thermocouples is about 0.5 wire diameter to minimize errors. As indicated by a simple parametric analysis, axial conduction is the predominant heat transfer mechanism. Therefore, experimental errors due to radial conduction are estimated to be less than 1%. A high temperature cement which has a high thermal conductivity but is electrically insulating is employed for this purpose. The thermocouple cold (reference) junctions are then soldered to thermocouple extension wires that pass through vacuum sealed holes in a removable plexiglass window of the arc chamber. The extension wires can either be connected through the cold junction compensator (hardware cold junction compensation) or directly (software cold junction compensation) to the amplifiers and then to the data acquisition board which is plugged into the PC. The output from the signal conditioning circuit is fed into analog input channels of the data acquisition board. Software routines using NIST (National Institute of Standards and Technology)

tion of the discharge, the arc discharge generates a large amount of heat and a part of it is deposited at the tip of the wire which melts the tip. The large temperature differential along the wire generates a temporally increasing conductive heat flux along the axis of the wire. This is indicated by the increasing temperatures recorded by the thermocouples.

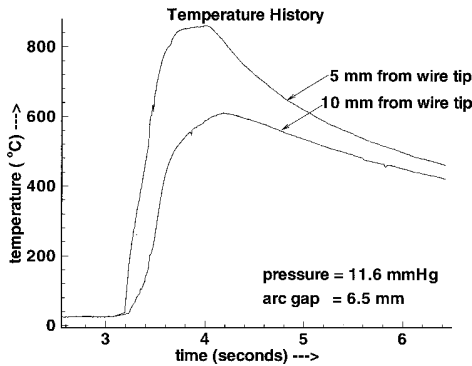


Figure 4. Temperature transient variation.

In Figure 5, a photomicrograph (50x) of the etched ball section is shown for a run with a mean discharge current of 12.9 A. The authors note the columnar grains formed due to the nature of the solidification process. Once the arc discharge is terminated, the heat flux at the ball surface almost instantaneously reverses direction as heat from the melt is lost by natural convection and conduction to the surrounding air. A few surface layers in this region get instantaneously quenched leading to a surface layer of very fine grains. However, the primary heat loss mechanism from the ball is still the heat conduction along the axis of the wire. Therefore, the solidification front progresses almost normal to the axis of the wire downwards away from the end of the melt region at the wire towards the interior of the ball. This has also been borne out in the recent studies by Huang et al.¹² and Cohen et al.²⁵ with an initially undeformed wire. This explains the columnar grains indicated in the figure. The line between the columnar grain region and the polyhedral grains indicates the location of the end of the melt region. In the photomicrograph, the authors can see evidence of some voids and a small amount of necking at the melt circumferential interface. From the photomicrographs and from observations made during the sectioning of the samples, the researchers are also able to estimate the void content for each ball. The ball shown in Figure 5 was deformed from sphericity by its weight. Clearly, a real scale copper ball would be (nearly) perfectly due to the extreme dominance of surface tension over gravity forces.²⁹ The voids that are visible also are due to the 60x enlargement of the experiment. These numerical simulations of solidification of molten balls showed that on the real (25 μm) scale conduction up the wire axis is so dominant that any potential shrinkage void would be pushed out the bottom of the ball before solidification. However, on the large scale, it is possible that there is just enough cooling through the sides of the ball to trap a shrinkage void within. In these two respects, Figure 5 does not represent a valid model of a real scale ball.

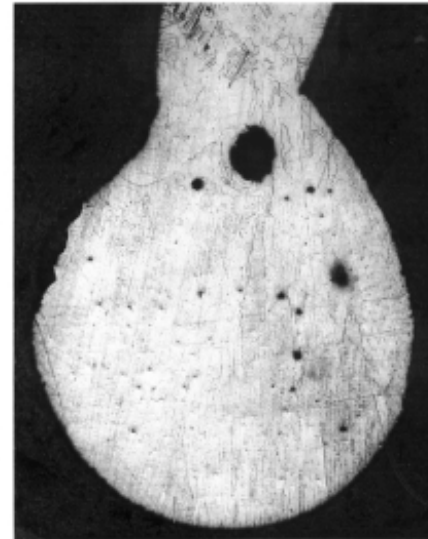


Figure 5. Photomicrograph of etched ball section.

In Figure 6, the authors present the photomicrograph of the etched wire longitudinal section for the same run as Figure 5. The section is at a distance from the ball which displays the extent of the Heat Affected Zone (HAZ). In the lower half of the picture, the grains are equiaxed and the grain boundaries are well defined. In the upper region, the grains are less defined and etch darkly. These observations lead to the conclusion that the lower part of the Figure which is toward the ball consists of recrystallized grains while the upper region of the figure corresponds to relatively unaffected regions. This indicates the extent of the HAZ relative to the ball. The researchers have recorded the extent of the HAZ for all the samples.

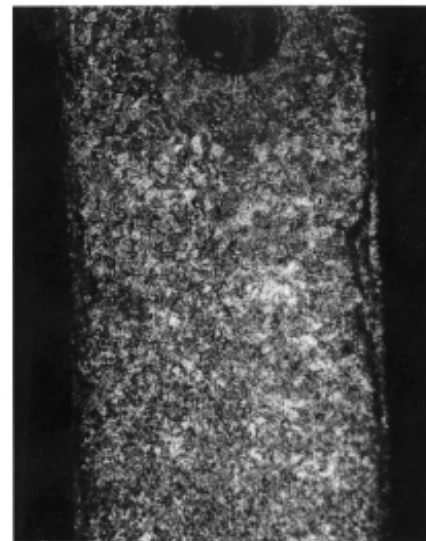


Figure 6. Photomicrograph of etched wire.

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The temperature histories and measured ball dimensions are used to calculate the time averaged arc heat transfer to the wire tip/ball during the discharge process. The method of calculation of the heat transfer is similar to that described by Cohen et al.²⁵ The authors summarized the method as follows. From the temperature history, one can compute the average heat transfer, Q_k , along the axis of the wire during the discharge as described in an earlier section. The latent heat of fusion is used to compute the energy of melting Q_m . The ball also undergoes heat loss by convection and radiation Q_{hr} to the surrounding air. The three quantities may then be summed to obtain the net heat input Q_w to the wire tip/ball. The integral of the power (IV) over the discharge duration gives the electrical energy, Q_a , consumed by the arc. The ratio of the heat input to the ball to the electrical energy consumed gives the fraction of the total energy consumed in ball formation. In Table 1, the researchers present the various heat quantities and the ratio of the heat input to the wire to the electrical energy consumed (Q_w/Q_a) for various values of average discharge currents and the corresponding arc durations t . The values represent calculations averaged over four runs at each setting in the arc chamber.

Table 1. Heat quantities for various currents.

I_w (A)	t (sec)	Q_w (J)	Q_a (J)	Q_w/Q_a
5.80	0.832	75.03	229.2	0.327
11.6	0.302	125.9	221.3	0.569
12.9	0.457	80.13	205.1	0.391
17.5	0.137	33.93	88.19	0.385
21.0	0.360	86.04	280.4	0.307

Figure 7 shows the variation of the voidage (volume void fraction) with the average discharge current (four runs at each current value) The curve shown is a parametric spline fit through the data. The trend in voidage shows a dramatic change because of the appearance of large shrinkage voids at the center of the ball for higher values of the discharge current. As noted above such voiding does not occur on the real scale. We report it here because it was an outcome of our experiments. In Figure 8, we present the variation in the length of the HAZ along the axis of the wire (referred to the tip of the bent wire) and non-dimensionalized by the wire diameter. The HAZ length shows a decreasing trend with increasing current. As the current increases, the arc duration required to form a ball decreases. This in turn implies there is less time available for heat effects (e.g. grain recrystallization) to penetrate axially along the wire away from the ball. Due to the finite thermal diffusivity of the metal, this would in turn imply the length of penetration of heat effects or the extent of HAZ would also decrease with higher currents.

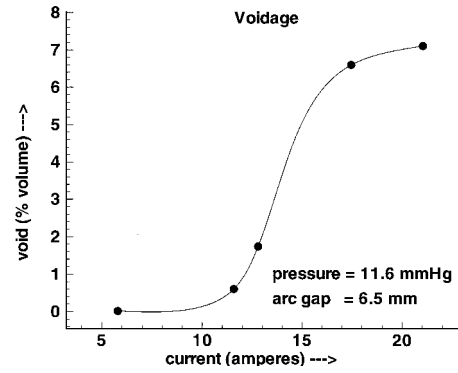


Figure 7. Variation of voidage with current.

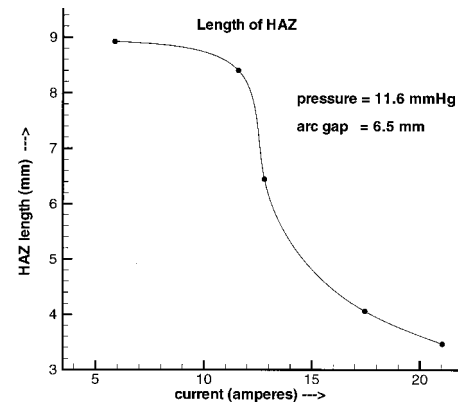


Figure 8. Variation of HAZ with current.

The voidage and HAZ variation are shown with current as the independent variable because, current is the major control variable in the discharge process.

6. Experimental Uncertainties

The uncertainty in the discharge voltage and current measurements is $\pm 1.5\%$. The uncertainty in the thermocouple temperature is $2.2\text{ }^\circ\text{C}$ or $\pm 0.75\%$ whichever is greater. The uncertainty in the temperature time history also depends on the response time for the thermocouples. The thermocouple response time is characterized by the rated time constant. The time constant leads to an estimated uncertainty of $\pm 3.5\%$ in the transient response for the experiments. An error analysis indicates that uncertainty in the heat flux calculations is $\pm 4.2\%$ due to propagation of uncertainties in measured data. The uncertainty in the HAZ length measurement is $\pm 2\%$. The maximum uncertainty is in the voidage estimates and is $\pm 7\%$.

7. Conclusions

The authors have made a comprehensive experimental and numerical study of the heat transfer associated with an electronic flame off discharge process used in microelectronic packaging. To simulate industrial situations, 60x enlarged scale bent wire samples were fabricated using a special capillary. The samples were used in the arc chamber and the discharge current was varied as the independent variable while keeping the pressure and arc gap constant. The entire discharge process is programmable through a personal computer.

Discharge current and voltage histories and characteristics were obtained. Implanted fine gage thermocouples were employed to obtain the temperature histories at two locations along the axis of the wire. The temperature histories and ball size measurements enabled the researchers to estimate the heat input to the wire. The balls so formed were also analyzed metallographically and representative photomicrographs have been presented. From the micrographs, estimates of the void content and extent of the Heat Affected Zone (HAZ) were obtained and have been presented. In order to form "good" balls, lower void content is desired. This limits the magnitude of the discharge current. However, owing to the demands for low chip profiles and consequently low wire loop heights, the HAZ length needs to be minimized. This requires higher discharge currents. These opposing trends of voidage and HAZ lengths with discharge current may be optimized to give the "best" design settings that would lead to "good" balls.

Acknowledgments

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focused on the electronic flame off discharge process for ball bonding from a computational modeling as well as an experimental perspective.



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